

FILE VIEW: [All Icons] Window Help

Active

L1: (2646) vertical near3 (MOS MOSFET)

L2: (150) 1 with (pitch or thickness)

L3: (66) 2 with (drain or source or channel)

L4: (501) 1 with (opening trenchS2 groove recessS2 trough)

L8: (177) 438/192

L9: (8) 8 and 4

L10: (175) 438/206

L11: (20) 10 and 4

L12: (16) 11 not 9

L13: (102) 438/173

L14: (5) 13 and 4

L15: (350) 438/212

L16: (33) 15 and 4

L17: (22) 16 not 11

L18: (257) 438/137, 138.ccls.

L19: (15) 18 and 4

L20: (15) 19 not 12

L21: (14) 20 not 17

L22: (12) 21 not 3

L23: (334) 438/156

L24: (12) 23 and 4

L25: (11) 24 not 22

L26: (102) 438/173

L27: (5) 26 and 4

L29: (177) 438/192

L30: (8) 29 and 4

L32: (785) 438/192, 206, 209, 212, 268.ccls.

L33: (55) 32 and 4

L34: (41) 33 not 17

L35: (37) 34 not 22

L36: (5643) 438/396

L37: (4) 36 and 4

L40: (0) 39 and 4

L41: (3745) 438/253

L42: (6) 41 and 4

L43: (699) 438/244

L44: (10) 43 and 4

L45: (3745) 438/253

L46: (6) 45 and 4

L47: (1658) vertical near3 MOS

L48: (475) (vertical near3 MOS).ab.

L49: (176) 48 and (drain or source or channel)

L50: (4) ("4740826" | "5443992" | "5920088" | "6153905").PN.

L51: (569) 438/269, 270.ccls.

L53: (98) 52 and 4

L55: (82) 53 not 35

L56: (69) 55 not 17

L57: (55) 56 not 40

Standard List Browse Queue Clear

DBs: JSPAT:US:PGPUB:EPD

Default operator: OR

☐ Search

☒ Highlight all hit terms initially

78 and 79

SRG term SAR term Image Text HTML

U	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval C	Inventor	S	C	P	S	In
	2004006117A/20040401		14	Pinfer having improved carri	257/350	257/328:		Lin, Ming-Ren et al.					

Ready

LAST - [0930132] wsp.1

File View Edit Tools Window Help

Search Find Review Queue Clear

DB: USPAT:US-PGRJUS:EPO

Default operator: DR

Highlight all hit terms initially

78 and 79

Failed

Saved

(3) ((("5208172") or ("5545586") or ("5376562"))).PN.

(4) ("4663831" | "4764801" | "4860077" | "4902641").PN.

(24) 5208172.URPN.

(2646) vertical near3 (MOS MOSFET)

(1736098) opening trench\$2 groove recess\$2 trough

(204276) (insulat\$3 dielectric) near (film layer)

(1463) (vertical near3 (MOS MOSFET)) and (opening trench\$2 groove recess\$2 trough) and ((insulat...

(560) ((vertical near3 (MOS MOSFET)) and (opening trench\$2 groove recess\$2 trough) and ((insulat...

(4789) (source and drain) with (sequence stack\$2)

(29) (((vertical near3 (MOS MOSFET)) and (opening trench\$2 groove recess\$2 trough) and ((insulat...

(9) ("4236166" | "4550489" | "4740826" | "4788158" | "5398200" | "5414655" | "5451800" | "549701...

(22) ("4364074" | "4653025" | "4740826" | "4794561" | "4821235" | "4890144" | "4920397" | "49299...

Favorites

Imported (1)

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U	1	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval C	Inventor	S	C	P	3	In
		20040061178	20040401	14	Finfer having improved carri	257/350	257/328		Gjn. Mino-Rap et al					

Ready

NUM